


## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:	§	
STARIKOV, et al.	§	Group Art Unit: <i>Unassigned</i>
Serial No.: <i>Unassigned</i>	§	
Filed: 08/18/2003	§	Examiner: <i>Unassigned</i>
Title: "ONE-CHIP MICRO-INTEGRATED OPTOELECTRONIC SENSOR"	§	Atty. Docket No.: 065238.0128

MAIL STOP PATENT APPLICATION  
Honorable Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

CERTIFICATE OF MAILING VIA EXPRESS MAIL 37 C.F.R. 1.10	
I HEREBY CERTIFY THAT I HAVE INFORMATION AND A REASONABLE BASIS FOR BELIEF THAT THIS CORRESPONDENCE IS BEING DEPOSITED WITH THE UNITED STATES POSTAL SERVICE AS EXPRESS MAIL POST OFFICE TO ADDRESSEE ON THE DATE INDICATED BELOW AND IS ADDRESSED TO: MAIL STOP PATENT APPLICATION HONORABLE COMMISSIONER FOR PATENTS P. O. Box 1450 ALEXANDRIA, VA 22313.1450	
 JULIE CLEMENTS	08.18.2003 DATE
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## TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT

Sir:

Applicants respectfully request, pursuant to 37 C.F.R. §§1.56, 1.97 and 1.98, that the art listed on the attached PTO-1449 form be considered and cited in the examination of the above-identified divisional patent application.

As this divisional is being filed after June 30, 2003, and in accordance with the U.S. Patent Office waiver of the requirement under 37 C.F.R. 1.98(a)(2)(i), copies of the cited U.S. patents are not enclosed; however, enclosed are copies of the four (4) non-patent literature documents cited on the attached P.T.O. Form 1449, for the convenience of the Examiner.

PTO-1449  Information Disclosure Citation in an Application			Application No. <b>Unassigned</b>		Applicant(s): <b>STARIKOV ET AL.</b>		
			Docket Number <b>065238.0128</b>		Group Art Unit	Filing Date <b>08/18/2003</b>	
<b>U.S. PATENT DOCUMENTS</b>							
		<b>DOCUMENT NO.</b>	<b>DATE</b>	<b>NAME</b>	<b>CLASS</b>	<b>SUBCLASS</b>	<b>FILING DATE</b>
	A	6,075,611	06/13/2000	DUSSAN V. ET AL.	356	432	05/07/1998
	B	6,034,404	03/07/2000	SOARES	257	415	12/05/1996
	C	5,955,972	09/21/1999	WADE	340	960	09/03/1997
	D	5,995,229	11/30/1999	OMI	356	374	09/22/1998
	E	5,990,500	11/23/1999	OKAZAKI	257	99	03/03/1999
	F	5,920,018	07/06/1999	WILKERSON, ET AL.	73	861.41	12/11/1996
	G	5,822,473	10/13/1998	MAGEL, ET AL.	385	12	02/28/1997
	H	5,591,963	01/07/1997	TAKEDA, ET AL.	250	214.1	08/08/1995
	I	5,442,169	08/15/1995	KUNZ	250	227.21	06/02/1993
	J	5,341,805	08/30/1994	STAVRIDIS ET AL.	128	633	04/06/1993
	K	5,202,571	04/13/1993	HIRABAYSHI, ET AL.	257	10	07/03/1991
	L	5,196,709	03/23/1993	BERNDT, ET AL.	250	458.1	05/03/1991
	M	5,082,629	01/21/1992	BURGESS, JR., ET AL.	422	82.11	12/29/1989
	N	4,900,373	02/13/1990	CHU, ET AL.	148	33.4	07/19/1989
<b>FOREIGN PATENT DOCUMENTS</b>							
		<b>DOCUMENT NO.</b>	<b>DATE</b>	<b>COUNTRY</b>	<b>CLASS</b>	<b>SUBCLASS</b>	<b>TRANSLATION</b>
							YES NO
<b>NON-PATENT DOCUMENTS</b>							
		<b>DOCUMENT (Including Author, Title, Source, and Pertinent Pages)</b>					<b>DATE</b>
	O	TEMPEZ, ET AL., "PHOTOENHANCED REACTIVE ION ETCHING OF III-V NITRIDES IN BCL <sub>3</sub> /CL <sub>2</sub> /AR/N <sub>2</sub> PLASMAS," <i>J. VAC. SCI. TECHNOL. A</i> 17(4), JUL/AUG 1999, PG. 2209-2213					1999
	P	MEDELICI, ET AL., "REACTIVE ION ETCHING OF BORON NITRIDE AND GALLIUM NITRIDE MATERIALS IN CL <sub>2</sub> /AR AND BCL <sub>3</sub> /CL <sub>2</sub> /AR CHEMISTRIES," MAT. RES. SOC. SYMP. PROC. VOL. 512, PG. 285-291					1998
	Q	STARIKOV, ET AL., "A HOT ELECTRONS-BASED WIDE SPECTRUM ON-ORBIT OPTICAL CALIBRATION SOURCE," SPACE TECHNOLOGY AND APPLICATIONS INTERNATIONAL FORUM-1998," PG. 648-653					1998
	R	STARIKOV, ET AL., "METAL-INSULATOR-SEMICONDUCTOR SCHOTTKY BARRIER STRUCTURES FABRICATED USING INTERFACIAL BN LAYERS GROWN ON GAN AND SiC FOR OPTOELECTRONIC DEVICE APPLICATIONS," <i>J. VAC. SCI. TECHNOL. A</i> 17(4), JUL/AUG 1999, PG. 1235-1238					1999
EXAMINER					DATE CONSIDERED		
EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.							

Furthermore, pursuant to 37 C.F.R. §§1.97(g) and (h), no representation is made that these references are material to the patentability of the present application.

This Information Disclosure Statement is being filed concurrently with the filing of this patent application, which is a division of, and claims priority to, commonly owned United States patent application serial number 09/738,728, filed December 15, 2000, entitled "One-Chip Micro-Integrated Optoelectronic Sensor," by David Starikov, Igor Berishev and Abdelhak Bensaoula, which will issue to United States Patent number 6,608,360 on August 19, 2003.

As the Information Disclosure Statement is being submitted before the mailing of the first office action on the merits, Applicants believe that no fee is required. However, should the Commissioner deem that any fee is due, Applicants respectfully request that the Commissioner accept this as a Petition Therefor, and further authorize the Commissioner to debit any fee which is due from Baker Botts L.L.P. Deposit Account No. 02-0383, Order No. 065238.0128.

Respectfully submitted,

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Date: August 18, 2003